## Introductory Nanotechnology <br> ~Basic Condensed Matter Physics ~



## Atsufumi Hirohata

## Department of Electronics

## The University of York <br> 

y.

Quick Review over the Last Lecture
3 states of matters :

|  | solid |  | liquid |  | gas |
| :--- | :--- | :--- | :--- | :--- | :--- |
| density | $($ | $)$ | $($ | $)$ | $\left(\begin{array}{l} \\ \text { ordering range }\end{array}\right.$ |
| ( | $)$ | $($ | $)$ |  |  |
| rigid time scale | $($ | $)$ | $($ | $)$ |  |

4 major crystals :
soft
solid
( ) (
) 1
)
(
)

## Contents of Introductory Nanotechnology

First half of the course :
Basic condensed matter physics

1. Why solids are solid?
2. What is the most common atom on the earth ?
3. How does an electron travel in a material ?
4. How does lattices vibrate thermally ?
5. What is a semi-conductor?
6. How does an electron tunnel through a barrier ?
7. Why does a magnet attract / retract ?
8. What happens at interfaces ?

Second half of the course
Introduction to nanotechnology (nano-fabrication / application)

## What Is the Most Common Atom <br> on the earth? <br> - Phase diagram <br> - Free electron model <br> - Electron transport <br> - Degeneracy <br> - Electron Potential <br> - Brillouin Zone <br> - Fermi Distribution



Mason (1966)
Only surface 10 miles (Clarke number)



W

## Major Phases of Fe

Fe changes the crystalline structures with temperature / pressure :


Free electrons :


Uncertainty principle :

$$
\Delta x \Delta p \geq \hbar \quad(x: \text { position and } p: \text { momentum })
$$

When a 3s electron is confined in one Na atom ( $\Delta x \approx r$ ):

$$
\begin{aligned}
& p \approx \Delta p \approx \hbar / r \\
& E=p^{2} / 2 m=(\hbar / r)^{2} / 2 m=\hbar^{2} / 2 m r^{2} \quad(m: \text { electron mass })
\end{aligned}
$$

For a free electron, $r \rightarrow$ large and hence $E \rightarrow$ small.


## Free Electron Model

Equilibrium state :


Free electrons :
mass $m$, charge $-q$ and velocity $v_{\mathrm{i}}$
Equation of motion along $\boldsymbol{E}$ :

$$
m \frac{d v_{i}}{d t}=-q \boldsymbol{E}
$$

Average over free electrons :
drift velocity : $v_{\mathrm{d}}$

For each free electron :
thermal velocity (after collision) : $v_{0 i}$
acceleration by $\boldsymbol{E}$ for $\tau_{i}$

$$
v_{i}=v_{0 i}=-\frac{q}{m} \boldsymbol{E} \boldsymbol{\tau}_{i}
$$

Average over free electrons :
collision time : $\tau$

$$
v_{\mathrm{d}}=-\frac{q \tau}{m} \boldsymbol{E}
$$

Using a number density of electrons $n$, current density $J$ :

$$
\boldsymbol{J}=\left(-v_{\mathrm{d}}\right) q n=q^{2} \frac{n}{m} \boldsymbol{E} \boldsymbol{\tau}
$$

Ohm's law :

$$
V=i R=i \frac{\rho \ell}{S} \quad \text { For a small area : } \Delta V=\Delta i \rho \frac{\Delta \ell}{\Delta S} \rightarrow \frac{\Delta V}{\Delta \ell}=\rho \frac{\Delta i}{\Delta S} \rightarrow \boldsymbol{E}=\rho \boldsymbol{J}
$$

where $\rho$ : electric resistivity (electric conductivity : $\sigma=1 / \rho$ )
By comparing with the free electron model :

$$
\begin{aligned}
& \boldsymbol{J}=q^{2} \frac{n}{m} \boldsymbol{E} \boldsymbol{\tau} \\
& \sigma=\frac{1}{\rho}=q^{2} \frac{n}{m} \boldsymbol{\tau}
\end{aligned}
$$

## Relaxation Time

Resistive force by collision :


Equation of motion :
with resistive force $m v / \tau$

$$
m \frac{d v}{d t}=-q E-\frac{m}{\tau} v
$$

For the initial condition :

$$
\begin{aligned}
& v=0 \text { at } t=0 \\
& \qquad v=-\frac{q \tau}{m} E[1-\exp (-t / \tau)]
\end{aligned}
$$

For a steady state ( $t \gg \tau$ ),

$$
v=-\frac{q \tau}{m} E
$$

$\tau$ : collision time

If $E$ is removed in the equation of motion:

$$
m \frac{d v}{d t}=-\frac{m}{\tau} v
$$

For the initial condition :

$$
\begin{aligned}
& v=v_{\mathrm{d}} \text { at } t=0 \\
& \quad v=v_{\mathrm{d}} \exp (-t / \tau)
\end{aligned}
$$


$\tau:$ relaxation time $=\langle t\rangle$

Equation of motion under E:

$$
m \frac{d v}{d t}=-q E
$$

Also,

$$
\left\langle t^{2}\right\rangle=\int_{0}^{\infty} \frac{t^{2}}{\tau} \exp \left(-\frac{t}{\tau}\right) d t=2 \tau^{2}
$$

For an electron at $\mathbf{r}$,
collision at $t=0$ and $\mathbf{r}=\mathbf{r}_{0}$ with $\mathrm{v}_{0}$

$$
\boldsymbol{r}-\boldsymbol{r}_{0}=\boldsymbol{v}_{0} t+\frac{1}{2} \frac{(-q) \boldsymbol{E}}{m} t^{2}
$$

Here, ergodic assumption :
temporal mean $=$ ensemble mean
Accordingly,

$$
\begin{aligned}
& \left\langle\boldsymbol{r}-\boldsymbol{r}_{0}\right\rangle=\frac{-q \boldsymbol{E}}{m} \boldsymbol{\tau}^{2} \\
& \frac{\left\langle\boldsymbol{r}-\boldsymbol{r}_{0}\right\rangle}{\boldsymbol{\tau}}=\frac{-q \tau}{m} \boldsymbol{E}=v_{\mathrm{d}}
\end{aligned}
$$

therefore, by taking an average over Finally, $v_{d}=-\mu \boldsymbol{E}$ is obtained.
non-collided short period,

$$
\mu=q \tau / m: \text { mobility }
$$

$$
\left\langle\boldsymbol{r}-\boldsymbol{r}_{0}\right\rangle=\left\langle\boldsymbol{v}_{0} t\right\rangle+\frac{-q \boldsymbol{E}}{2 m}\left\langle t^{2}\right\rangle
$$

Since $t$ and $v_{0}$ are independent,

$$
\left\langle v_{0} t\right\rangle=\left\langle\boldsymbol{v}_{0}\right\rangle\langle t\rangle
$$

Here, $\left\langle\boldsymbol{v}_{0}\right\rangle=0$, as $v_{0}$ is random.

## Degeneracy

For H-H atoms :



Electron Potential Energy
Potential energy of an isolated atom (e.g., Na) :


Potential energy in a crystal (e.g., N Na atoms) :


- Potential energy changes the shape inside a crystal.
- 3s state forms $N$ energy levels $\rightarrow$ Conduction band


## Free Electrons in a Solid

Free electrons in a crystal :


Total electron energy


Wave / particle duality of an electron :
Wave nature of electrons was predicted by de Broglie,
and proved by Davisson and Germer

|  |  | Particle nature | Wave nature |
| :---: | :---: | :---: | :---: |
| Kinetic energy | $m v^{2} / 2$ | $h v=\hbar \omega$ |  |
| Momentum | $m v$ | $h / \lambda=\hbar k$ |  |

$$
\lambda=\frac{h}{p}=\frac{h}{m v} \quad(h: \text { Planck's constant })
$$

$\hbar=h / 2 \pi, \omega=2 \pi v, k=2 \pi / \lambda$

Bragg's law : $n \lambda=2 d \sin \theta$


For $\theta \sim 90^{\circ}(\pi / 2)$,

$$
n \lambda \approx 2 a
$$

Therefore, no travelling wave for

$$
k=\frac{2 \pi}{\lambda}=\frac{n \pi}{a} \quad n=1,2,3, \ldots
$$

$\rightarrow$ Forbidden band
Allowed band :

$$
-\frac{\pi}{a} \leq k \leq \frac{\pi}{a}
$$

$\rightarrow$ 1st Brillouin zone

In general, forbidden bands are

$$
k=\frac{2 \pi}{\lambda}=\frac{n \pi}{d \sin \theta} \equiv k_{n} n=1,2,3, \ldots
$$



## Periodic Potential in a Crystal



Energy band diagram
(reduced zone)
$\leftrightarrow$ extended zone

名
Brillouin zone : In a 3d $\mathbf{k}$-space, area where $\mathbf{k} \neq 0$.

For a 2D square lattice,


$$
k_{x} n_{x}+k_{y} n_{y}=\frac{\pi}{a}\left(n_{x}^{2}+n_{y}^{2}\right)
$$

$$
n_{x}, n_{y}=0, \pm 1, \pm 2, \ldots
$$

1st Brillouin zone is defined by
$n_{x}=0, n_{y}= \pm 1 \rightarrow k_{x}= \pm \pi / a$
$n_{x}= \pm 1, n_{y}=0 \rightarrow k_{y}= \pm \pi / a$


2nd Brillouin zone is defined by

$$
\begin{aligned}
& n_{x}= \pm 1, n_{y}= \pm 1 \\
& \rightarrow \pm k_{x} \pm k_{y}=2 \pi / a
\end{aligned}
$$

Reciprocal lattice:



Figure 1 Free electron Fermi surfaces for fee metals with one ( Cu ) and three ( A ) valence electrons per primitive cell. The Fermi surface shown for copper has been deformed from a sphere to agree with the experimental results. The second zone of aluminum is nearly half-filled with electrons. (A. R. Mackintosh.)

Fermi-Dirac distribution :


Pauli exclusion principle
At temperature T, probability that one energy state E is occupied by an electron :

$$
f(E)=\frac{1}{\exp \left[(E-\mu) / k_{\mathrm{B}} T\right]+1}
$$

$\mu$ : chemical potential ( = Fermi energy $\mathrm{E}_{\mathrm{F}}$ at $\mathrm{T}=0$ )
$k_{\mathrm{B}}$ : Boltzmann constant


## Fermi-Dirac / Maxwell-Boltzmann Distribution

Electron number density :
(a)

( $\mathrm{a}^{\prime}$ )

(b)

(b')
Fermi sphere :
$f(\epsilon)=\frac{1}{e^{\pi} \pi=\frac{1}{2}, v^{2},+1}$
(c)

(c)


Maxwell-Boltzmann distribution
(small electron number density)
Fermi-Dirac distribution
(large electron number density)

Fermi wave number $k_{\mathrm{F}}$ represents $E_{\mathrm{F}}$ :

$$
\begin{aligned}
& \text { Fermi velocity : } v_{\mathrm{F}}=\sqrt{\frac{2 E_{\mathrm{F}}}{m}} \\
& k_{\mathrm{F}}=\frac{m}{\hbar} v_{\mathrm{F}}=\frac{\sqrt{2 m E_{\mathrm{F}}}}{\hbar}
\end{aligned}
$$

Under an electrical field :
Electrons, which can travel, has an energy of $\sim E_{\mathrm{F}}$ with velocity of $v_{\mathrm{F}}$
For collision time $\tau$, average length of electrons path without collision is

$$
\ell=v_{\mathrm{F}} \tau \quad \text { Mean free path }
$$

Density of states:
Number of quantum states at a certain energy in a unit volume

$$
g(E)=2 \frac{1}{(2 \pi)^{3}} \frac{4 \pi}{2}\left(\frac{2 m}{\hbar^{2}}\right)^{3 / 2} \sqrt{E} d E
$$



## Density of States (DOS) and Fermi Distribution

Carrier number density $n$ is defined as :

$$
n=\int f(E) g(E) d E
$$




